

TR0329M

2.0-4.2 GHz GaAs Ultra Low Noise 2 Stage Bypassed LNA

Application Note: TR0329M EVB B

Application Note 2300 MHz~2700 MHz 5.0 V, 90 mA-HG mode 5.0 V, 45 mA-LG mode

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1. General Description

The TR0329M is a high-linearity, ultra-low noise 2-stage gain block amplifier module with internal 50ohm input output matching with a bypass mode functionality integrated to the second stage in the product. At 3.6 GHz, the amplifier, under high gain mode, typically provides 34 dB gain, +35 dBm OIP3, and 0.5 dB noise figure while drawing 90 mA current from a +5 V supply. The component also provides high performance in the low gain mode with 15 dB gain, 0.5 dB noise figure and +22 dBm OIP3 while drawing 50 mA current. The TR0329M is packaged in a compact, low-cost Quad Flat No Lead (QFN) 3.5 x 3.5 x 0.75 mm, 20 pin plastic packages.

TR0329M-EVB-B is an evaluation board specially tuned for frequency range of 2300 MHz~2700 MHz applications. Its application in the areas of Wireless infrastructure, TDD massive multiple input & multiple output, active antenna systems, TDD-based communication systems etc.



2. TR0329M-EVB-B Board Details

Figure 2.1 TR0329M-EVB-B 2300 MHz ~ 2700 MHz Schematic and EVB Layout



3. TR0329M-EVB-B Bill of Materials

Component ID	Value	Manufacturer	Recommended Part Number	Qty
R1, R2	0 Ω	Panasonic	ERJ-2GE0R00X	2
C7	6.8 pF	Murata	GJM1555C1H6R8BB01D	1
M2, M1	220 pF	Kemet	C0402C221K5GACAUTO	2
C2, C5, C9, C10	100 pF	AVX	04025A101JAT4A	4
C1, C4, C8, C11	100 nF	TDK	C1005X7R1H104K050BE	4
C3, C6	1.5 nF	Murata	04025C152JAT2A	2
R4	15 Ω	Panasonic	ERJ-H2RD15R0X	1
R3	150 Ω	Panasonic	ERJ-2RHD1500X	1
L1, L2	8.2 nH	Coil craft / Wurth Electronics	0402HP-8N2XGE / 744916082	2
PCB	Rogers RO4350B, 20 mils, 1 oz copper			1

Table 3.1 TR0329M-EVB-B BOM

4. TR0329M-EVB-B Biasing Sequence

Turn ON Device	Turn OFF Device		
 Apply bias to the VDD1 and VDD2=5 V test points. Apply bias to the BP test points. Apply bias to the PD test point. Apply an RF input signal. 	 Turn RF power off. Turn off VDD1 and VDD2=5 V test points. Turn off BP and PD 		

Table 4.1 TR0329M-EVB-B Bias and Sequencing

5. TR0329M-EVB-B Board Measurement Summary

Parameter	Test Condition	Typical Values	Unit
Operational frequency Range		2.3-2.7	GHz
Cain	HG	37-36.8	dB
Gain	LG	18-16.7	dB
Noise Figure (De embedded)	HG	0.5-0.6	dB
Noise Figure (De-embedded)	LG	0.5-0.6	dB
EV/B Naisa Figura	HG	0.6-0.7	dB
EVB Noise Figure	LG	0.6-0.7	dB
Input Poturn Loop	HG	Less than -11	dB
	LG	Less than -11	dB
Output Datura Laga	HG	Less than -11	dB
	LG	Less than –5.5	dB
	HG	17-18.5	dBm
OPTUB	LG	10-12	dBm
OID2 (With 1MHz topo oppoing)	0 dBm per tone,	30-31	dBm
OIPS (WITH INITZ tone spacing)	-2 dBm per tone,	21-23	dBm
	HG	90	mA
Current, Id	LG	45	
	PD	5	
Isolation between RFIN and RF-out	At 2.5 GHz Receive operation	55	dB
PD mode ON and Bypass ON			
Isolation between RFIN and RF-out PD mode ON and High Gain ON		50	dB

Table 5.1 TR0329M-EVB-B Electrical Characteristics Summary

Application Note: TR0329M EVB B



6. TR0329M-EVB-B Test Results

All the tests are carried out at room temperature.

6.1. S parameters



Figure 6.1.1. S parameters of HG mode of TR0329M-EVB-B



Figure 6.1.2 S parameters of LG mode of TR0329M-EVB-B



6.2. De-embedded Noise Figure



Figure 6.2.1 De-embedded NF of HG mode of of TR0329M-EVB-B





Figure 6.3.1. Gain Vs Pout of HG mode of TR0329M-EVB-B



Figure 6.3.3. Gain compression Vs Pout of HG mode of TR0329M-EVB-B



Figure 6.2.2 De-embedded NF of LG mode of TR0329M-EVB-B



Figure 6.3.2. Gain Vs Pout of LG mode of TR0329M-EVB-B



Figure 6.3.4. Gain compression Vs Pout of LG mode of TR0329M-EVB-B





Figure 6.3.5. OIP3 Vs Pout per tone of HG mode of TR0329M-EVB-B



Figure 6.3.6. OIP3 Vs Pout per tone of LG mode of TR0329M-EVB-B



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